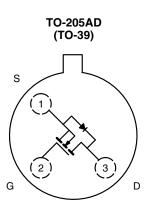
www.vishay.com

## 2N6661, 2N6661-2, 2N6661JANTX, 2N6661JANTXV

**Vishay Siliconix** 

# N-Channel 90 V (D-S) MOSFET

PRODUCT SUMMARY					
V <sub>DS</sub> (V)	90				
$R_{DS(on)} (\Omega)$ at $V_{GS} = 10 V$	4				
Configuration	Single				



#### Top View

### **FEATURES**

- Military Qualified
- Low On-Resistence: 3.6 Ω
- Low Threshold: 1.6 V
- Low Input Capacitance: 35 pF
- Fast Switching Speed: 6 ns
- Low Input and Output Leakage

## BENEFITS

- Guaranteed Reliability
- · Low Offset Voltage
- Low-Voltage Operation
- · Easily Driven Without Buffer
- High-Speed Circuits
- Low Error Voltage

### APPLICATIONS

- Hi-Rel Systems
- Direct Logic-Level Interface: TTL/CMOS
- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories, Transistors, etc.
- Battery Operated Systems
- Solid-State Relays

ORDERING INFORMATION				
PART	PACKAGE	DESCRIPTION/DSCC PART NUMBER	VISHAY ORDERING PART NUMBER	
2N6661		Commercial	2N6661	
		Commercial, Lead (Pb)-free	2N6661-E3	
2N6661-2		See -2 Flow Document	2N6661-2	
2N6661JANTX	TO-205AD	JANTX2N6661 (std Au leads)	2N6661JTX02	
	(TO-39)	JANTX2N6661 (with solder)	2N6661JTXL02	
		JANTX2N6661P (with PIND)	2N6661JTXP02	
2N6661JANTXV		JANTXV2N6661 (std Au leads)	2N6661JTXV02	
		JANTXV2N6661P (with PIND)	2N6661JTVP02	

ABSOLUTE MAXIMUM RATINGS	$(T_A = 25 \ ^{\circ}C, \text{ unless other})$	rwise noted)			
PARAMETER	SYMBOL	LIMIT	UNIT		
Drain-Source Voltage		V <sub>DS</sub>	90	- v	
Gate-Source Voltage		V <sub>GS</sub>	± 20	v	
Continuous Drain Current (T <sub>J</sub> = 150 $^{\circ}$ C)	T <sub>C</sub> = 25 °C	I <sub>D</sub>	0.86		
	T <sub>C</sub> = 100 °C	ID	0.54	А	
Pulsed Drain Current <sup>a</sup>	I <sub>DM</sub>	3			
Maximum Power Dissipation	T <sub>C</sub> = 25 °C	D	6.25	14/	
	T <sub>A</sub> = 25 °C	- P <sub>D</sub> -	0.725	W	
Thermal Resistance, Junction-to-Ambient <sup>b</sup>		R <sub>thJA</sub>	170	00.004	
Thermal Resistance, Junction-to-Case		R <sub>thJC</sub>	20	°C/W	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150	°C	

Notes

a. Pulse width limited by maximum junction temperature.

b. Not required by military spec.





www.vishay.com

Vishay Siliconix

SPECIFICATIONS (T <sub>A</sub> = 25 °C	C, unless d	otherwise not	ed)					
						LIMITS		
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP. <sup>b</sup>	MAX.	UNIT	
Static								
Drain-Source Breakdown Voltage	V <sub>DS</sub>	V <sub>DS</sub>	= 0 V, I <sub>D</sub> = 10	) μΑ	90	125	-	
		$V_{DS} = V_{GS}, I_D = 1 \text{ mA}$		0.8	1.6	2	v	
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>		T <sub>A</sub> = - 55 °C		-	1.8	2.5	v
				T <sub>A</sub> = 125 °C	0.3	1.3	-	
Cata Rady Laskage	1	$V_{GS} = \pm 20 V$	V <sub>DS</sub>	$_{S} = 0 V$	-	- ± 100		
Gate-Body Leakage	I <sub>GSS</sub>			T <sub>A</sub> = 125 °C	-	-	± 500	nA
		$V_{GS} = 0 V$	V <sub>DS</sub>	= 72 V	-	-	1	μA
Zero Gate Voltage Drain Current	DSS			T <sub>A</sub> = 125 °C	-	-	100	
On-State Drain Current <sup>b</sup>	I <sub>D(on)</sub>	$V_{GS} = 10 V$	V <sub>DS</sub>	= 10 V	-	1.8	-	mA
	R <sub>DS(on)</sub>	$V_{GS} = 5 V$	I <sub>D</sub> = 0.3 A		-	3.8	5.3	Ω
Drain-Source On-State Resistance <sup>b</sup>		V <sub>GS</sub> = 10 V	I <sub>D</sub> = 1 A		-	3.6	4	
				$T_A = 125 \ ^\circ C^d$	-	6.7	7.5	-
Forward Transconductance <sup>b</sup>	g <sub>fs</sub>	V <sub>DS</sub> =	7.5 V, I <sub>D</sub> = 0.475 A		170	340	-	mS
Diode Forward Voltage	V <sub>SD</sub>	$V_{GS} = 0 V$	I <sub>S</sub> =	0.86 A	0.7	0.9	1.4	V
Dynamic	•		•			•		
Input Capacitance	Ciss				-	35	50	
Output Capacitance	C <sub>oss</sub>	<u> </u>	$V_{DS} = 25 V$ , f = 1 MHz		-	15	40	pF
Reverse Transfer Capacitance	C <sub>rss</sub>	$V_{GS} = 0 V$			-	2	10	
Drain-Source Capacitance	C <sub>ds</sub>				-	30	-	
Switching <sup>c</sup>	•		•			•	•	•
Turn-On Time	t <sub>ON</sub>	V <sub>DD</sub> =	= 25 V, R <sub>L</sub> = 2	23 Ω	-	6	10	
Turn-Off Time	t <sub>OFF</sub>	$I_D \cong 1 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 23 \Omega$		-	8	10	ns	

Notes

a. FOR DESIGN AID ONLY, not subject to production testing.

b. Pulse test: PW  $\leq$  300  $\mu s$  duty cycle  $\leq$  2 %.

c. Switching time is essentially independent of operating temperature.

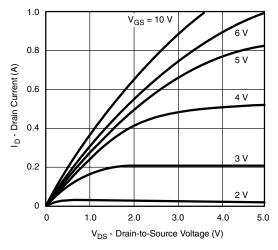
d. This parameter not registered with JEDEC.

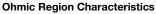
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

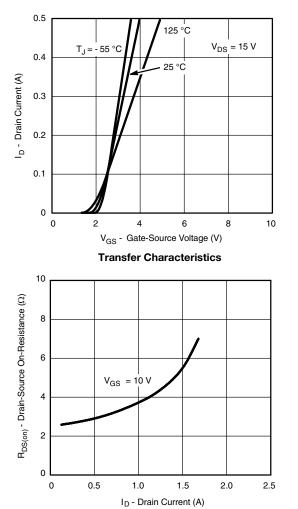
2N6661, 2N6661-2, 2N6661JANTX, 2N6661JANTXV www.vishay.com

Vishay Siliconix

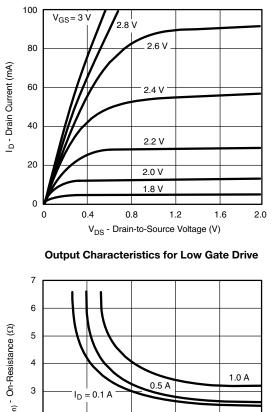
## TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

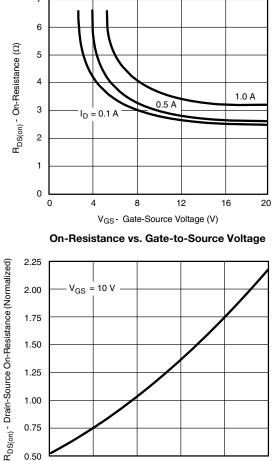






**On-Resistance vs. Drain Current** 





1.25 1.00 0.75 0.50 - 50 - 10 30 70 110 150 T<sub>J</sub> - Junction Temperature (°C) Normalized On-Resistance

vs. Junction Temperature

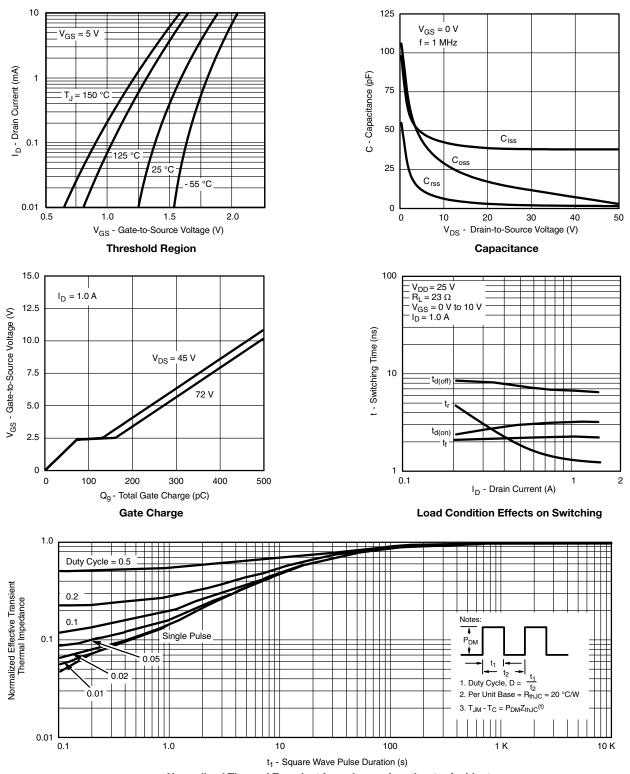
S11-1542-Rev. D, 01-Aug-11

## 2N6661, 2N6661-2, 2N6661JANTX, 2N6661JANTXV

www.vishay.com

**Vishay Siliconix** 

## TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <a href="http://www.vishay.com/ppg270225">www.vishay.com/ppg270225</a>.

S11-1542-Rev. D, 01-Aug-11

4

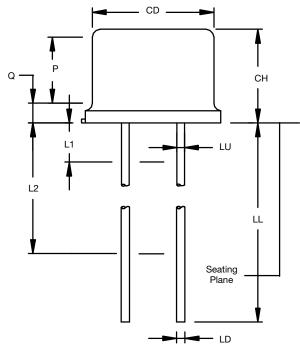
Document Number: 70225

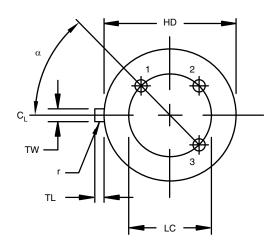
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <a href="http://www.vishay.com/doc?91000">www.vishay.com/doc?91000</a>



**Vishay Siliconix** 

**TO-205AD (TO-39 TALL LID)** 





DIM.	INC	HES	MILLIN	IETERS	
	MIN.	MAX.	MIN.	MAX.	
CD	0.305	0.335	7.75	8.51	
CH	0.240	0.260	6.10	6.60	
HD	0.335	0.370	8.51	9.40	
LC <sup>(6)</sup>	0.20	0 TP	5.08	3 TP	
LD <sup>(7)(8)</sup>	0.016	0.021	0.41	0.53	
LL (7)(8)	0.500	0.750	12.70	19.05	
LU (7)(8)	0.016	0.019	0.41	0.48	
L1 <sup>(7)(8)</sup>	_	0.050		1.27	
L2 <sup>(7)(8)</sup>	0.250		6.35	—	
P <sup>(5)</sup>	0 (5) 0.100		2.54	—	
Q <sup>(4)</sup>	_	0.050		1.27	
r <sup>(9)</sup>	_	0.010		0.25	
TL <sup>(3)</sup>	0.029	0.045	0.74	1.14	
TW <sup>(2)</sup>	0.028	0.034	0.71	0.86	
α (6)	45°	' TP	45° TP		
N: S15-1675-Rev. D, 2 G: 5511			<u> </u>		

#### Notes

<sup>(1)</sup> Dimensions are in inches. Metric equivalents are given for general information only.

<sup>(2)</sup> Beyond radius (r) maximum, TW shall be held for a minimum length of 0.011" (0.028 mm).

<sup>(3)</sup> Dimension TL measured from maximum HD.

<sup>(4)</sup> Outline in this zone is not controlled.

<sup>(5)</sup> Dimension CD shall not vary more than 0.010 (0.25 mm) in zone P. This zone is controlled for automatic handling.

(6) Leads at guage plane 0.054<sup>ii</sup> + 0.001<sup>ii</sup>, - 0.000<sup>ii</sup> (1.37 mm + 0.03 mm, - 0.00 mm) below seating plane shall be within 0.007<sup>ii</sup> (0.18 mm) radius of true position (TP) at maximum material condition (MMC) relative to tab at MMC.

<sup>(7)</sup> LU applies between L1 and L2, LD applies between L2 and L maximum.

Diameter is uncontrolled in L1 and beyond LL minimum.

(8) All three leads.

- <sup>(9)</sup> Radius (r) applies to both inside corners of tab.
- <sup>(10)</sup> Drain is electrically connected to the case.

Revison: 27-Jul-15



Vishay

# Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.